

Switchmode Power Rectifiers

Designed for use in switching power supplies, inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- * High Surge Capacity
- * Low Power Loss, High efficiency
- * Glass Passivated chip junctions
- * 150 Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction
- * Low Forward Voltage , High Current Capability
- * Ultrafast 50 & 75 Nanosecond Recovery Time
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

Plating pb free

The marking is indicated by part no. + "M". ex:SF17M~SF110M

MAXIMUM RATINGS

Characteristic	Symbol	SF17	SF18	SF19	SF110	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{R50}	500	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	350	420	560	700	V
Average Rectifier Forward Current	I_O	1.0				A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfwave, single phase,60Hz)	I_{FSM}	25				A
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-65 to +150				

ELECTRIAL CHARACTERISTICS

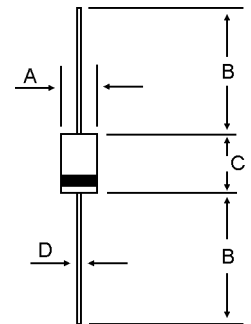
Characteristic	Symbol	SF17	SF18	SF19	SF110	Unit
Maximum Instantaneous Forward Voltage ($I_F=1.0$ Amp, $T_C = 25$)	V_F	1.50		1.75		V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25$) (Rated DC Voltage, $T_C = 125$)	I_R		5.0 50			μ A
Reverse Recovery Time ($I_F = 0.5$ A, $I_R = 1.0$, $I_{rr} = 0.25$ A)	T_{rr}		50		75	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & $f=1$ MHz)	C_P	15		10		pF

ULTRAFAST
RECTIFIERS

1.0 AMPERES
500-1000 VOLTS



DO-41(SOD-57)



DIM	MILLIMETERS	
	MIN	MAX
A	2.00	2.70
B	25.40	
C	4.10	5.20
D	0.70	0.90

CASE---
Transfer molded
plastic

POLARITY---
Cathode indicated
polarity band

SF17 Thru SF110

FIG-1 TYPICAL FORWARD CHARACTERISTICS

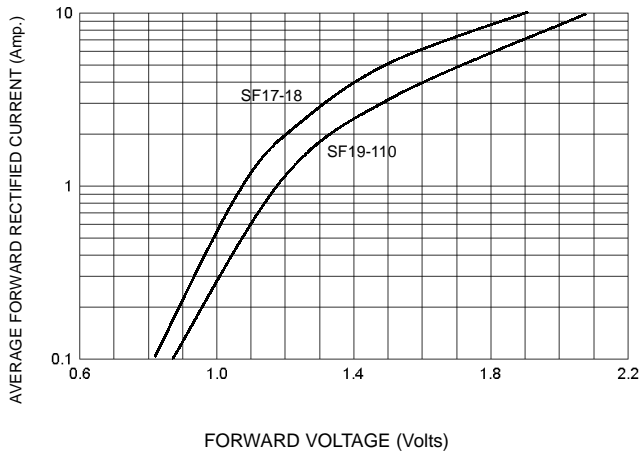


FIG-3 FORWARD CURRENT DERATING CURVE

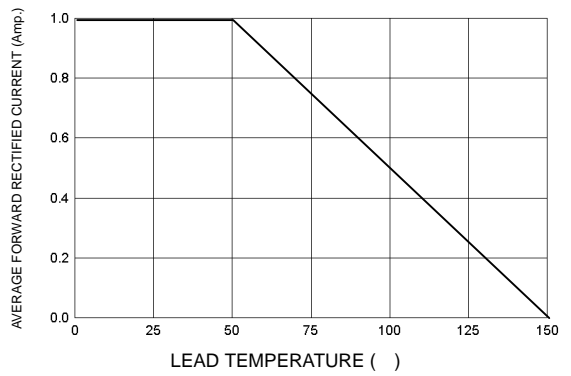


FIG-2 TYPICAL REVERSE CHARACTERISTICS

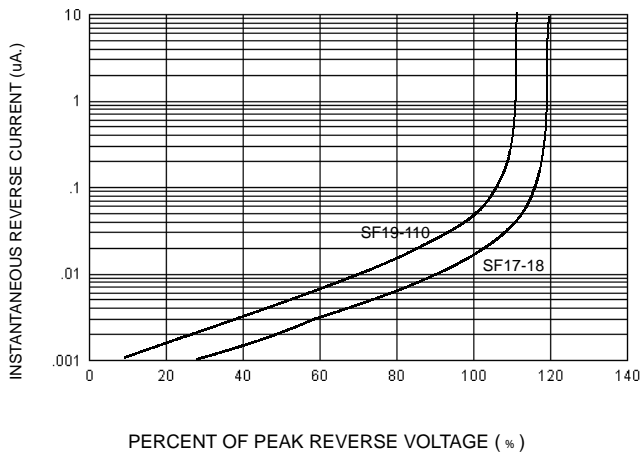


FIG-4 TYPICAL JUNCTION CAPACITANCE

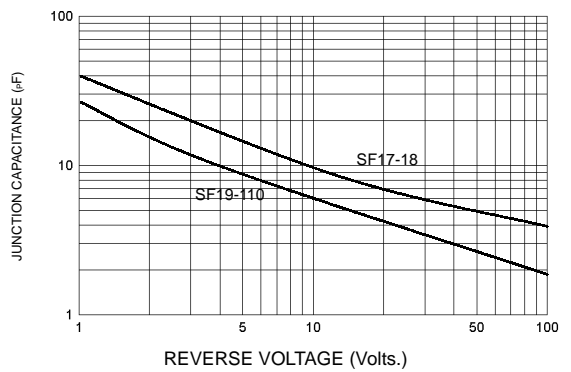
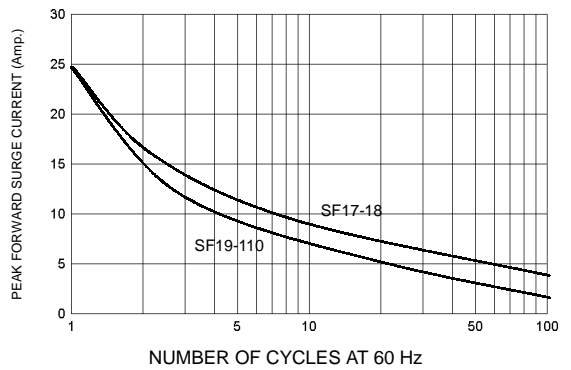
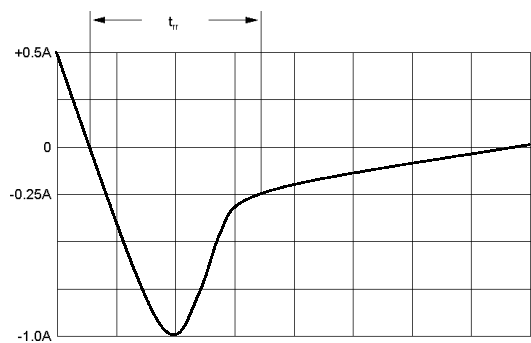


FIG-5 PEAK FORWARD SURGE CURRENT



- Notes:
 1. Rise Time = 7 ns max. Input Impedance = 1 M Ω , 22 pF
 2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

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